NSN 5962-01-236-6685

Memory Microcircuit - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5962-01-236-6685

Body Length:	
0.840 inches	
Body Width:	
Between 0.220 inches	and 0.310 inches
Body Height:	
0.185 inches	
Maximum Power Dis	sipation Rating:
794.0 milliwatts	
Operating Tempurat	ure Range:
-55.0/+125.0 degrees	celsius
Storage Tempurature	Range:
-65.0/+150.0 degrees	celsius
Features Provided:	
Hermetically sealed a	nd burn in and programmable and schottky and 3-state output
Inclosure Material:	
Ceramic	
Inclosure Configurat	ion:
Dual-in-line	
Output Logic Form:	
Transistor-transistor lo	gic
Input Circuit Pattern	
10 input	
Case Outline Source	And Designator:
D-2 mil-m-38510	
Terminal Surface Tre	atment:
Solder	
Voltage Rating And ⁻	Type Per Characteristic:
-0.5 volts power sour	ce and 7.0 volts power source
Time Rating Per Cha	cteristic:
85.00 nanoseconds p	ropagation delay time, low to high level output and 85.00 nanoseconds propagation delay time, high to low level
output	
Memory Device Type	c .
Prom	
Memory Capacity:	
Unknown	
Test Data Document	
96906-mil-std-883 sta	ndard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And G	luantity:
16 printed circuit	
Shelf Life:	
N/a	
Unit Of Measure:	

NSN 5962-01-236-6685

Memory Microcircuit - Page 2 of 2

Demilitarization:

No

Fiig:

A458a0

